

The 2N3954A is a Low Noise, Low Drift, Monolithic Dual N-Channel JFET

The 2N3954A family are matched JFET pairs for differential amplifiers. The 2N3954A family of general purpose JFETs is characterized for low and medium frequency differential amplifiers requiring low offset voltage, drift, noise and capacitance

The 2N3954A family also exhibits low capacitance - 6pF max and a spot noise figure of -0.5dB max. The part offers a superior tracking ability.

The hermetically sealed TO-71 and TO-78 packages are well suited for high reliability and harsh environment applications.

(See Packaging Information).

2N3954A Applications:

- Wideband Differential Amps
- High Input Impedance Amplifiers

FEATURES

| | |
|-------------|---|
| LOW DRIFT | $ \Delta V_{GS1-2} / \Delta T = 5\mu V/^{\circ}C$ max. |
| LOW LEAKAGE | $I_G = 20pA$ TYP. |
| LOW NOISE | $e_n = 10nV/\sqrt{Hz}$ TYP. |

ABSOLUTE MAXIMUM RATINGS @ 25°C (unless otherwise noted)

Maximum Temperatures

| | |
|--------------------------------|-----------------|
| Storage Temperature | -65°C to +200°C |
| Operating Junction Temperature | +150°C |

Maximum Voltage and Current for Each Transistor – Note 1

| | | |
|-------------|---------------------------------|------|
| $-V_{GSS}$ | Gate Voltage to Drain or Source | 60V |
| $-V_{DSO}$ | Drain to Source Voltage | 60V |
| $-I_{G(f)}$ | Gate Forward Current | 50mA |

Maximum Power Dissipation

| | |
|---------------------------------------|--------------|
| Device Dissipation @ Free Air – Total | 400mW @ 25°C |
|---------------------------------------|--------------|

MATCHING CHARACTERISTICS @ 25°C UNLESS OTHERWISE NOTED

| SYMBOL | CHARACTERISTICS | VALUE | UNITS | CONDITIONS |
|------------------------|-----------------------|-------|-------------------|---|
| $ V_{GS1-2} / T $ max. | DRIFT VS. TEMPERATURE | 5 | $\mu V/^{\circ}C$ | $V_{DG}=20V, I_D=200\mu A$ $T_A=-55^{\circ}C$ to $+125^{\circ}C$ |
| $ V_{GS1-2} $ max. | OFFSET VOLTAGE | 5 | mV | $V_{DG}=20V, I_D=200\mu A$ |

ELECTRICAL CHARACTERISTICS @ 25°C (unless otherwise noted)

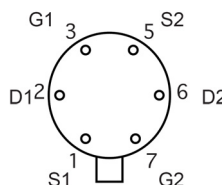
| SYMBOL | CHARACTERISTICS | MIN. | TYP. | MAX. | UNITS | CONDITIONS |
|------------------------------|---------------------------------|------|------|------|-----------------|---|
| BV_{GSS} | Breakdown Voltage | 60 | -- | -- | V | $V_{DS} = 0$ $I_D=1\mu A$ |
| BV_{GGO} | Gate-To-Gate Breakdown | 60 | -- | -- | V | $I_G = 1nA$ $I_D = 0$ $I_S = 0$ |
| TRANSCONDUCTANCE | | | | | | |
| Y_{fss} | Full Conduction | 1000 | 2000 | 3000 | μmho | $V_{DG} = 20V$ $V_{GS} = 0V$ $f = 1kHz$ |
| Y_{fs} | Typical Operation | 500 | 700 | 1000 | μmho | $V_{DG} = 20V$ $I_D = 200\mu A$ |
| $ Y_{FS1-2} / Y_{FS} $ | Mismatch | -- | 0.6 | 3 | % | |
| DRAIN CURRENT | | | | | | |
| I_{DSS} | Full Conduction | 0.5 | 2 | 5 | mA | $V_{DG} = 20V$ $V_{GS} = 0V$ |
| $ I_{DSS1-2} / I_{DSS} $ | Mismatch at Full Conduction | -- | 1 | 5 | % | |
| GATE VOLTAGE | | | | | | |
| $V_{GS(off)}$ or V_p | Pinchoff voltage | 1 | 2 | 4.5 | V | $V_{DS} = 20V$ $I_D = 1nA$ |
| $V_{GS(on)}$ | Operating Range | 0.5 | -- | 4 | V | $V_{DS} = 20V$ $I_D = 200\mu A$ |
| GATE CURRENT | | | | | | |
| $-I_G$ | Operating | -- | 20 | 50 | pA | $V_{DG} = 20V$ $I_D = 200\mu A$ |
| $-I_G$ | High Temperature | -- | -- | 50 | nA | $T_A = +125^{\circ}C$ |
| $-I_G$ | Reduced V_{DG} | -- | 5 | -- | pA | $V_{DG} = 10V$ $I_D = 200\mu A$ |
| $-I_{GSS}$ | At Full Conduction | -- | -- | 100 | pA | $V_{DG} = 20V$ $V_{DS} = 0$ |
| OUTPUT CONDUCTANCE | | | | | | |
| Y_{OSS} | Full Conduction | -- | -- | 5 | μmho | $V_{DG} = 20V$ $V_{GS} = 0V$ |
| Y_{OS} | Operating | -- | 0.1 | 1 | μmho | $V_{DG} = 20V$ $I_D = 200\mu A$ |
| $ Y_{OS1-2} $ | Differential | -- | 0.01 | 0.1 | μmho | |
| COMMON MODE REJECTION | | | | | | |
| CMR | $-20 \log V_{GS1-2} / V_{DS} $ | -- | 100 | -- | dB | $\Delta V_{DS} = 10$ to $20V$ $I_D = 200\mu A$ |
| CMR | $-20 \log V_{GS1-2} / V_{DS} $ | -- | 75 | -- | dB | $\Delta V_{DS} = 5$ to $10V$ $I_D = 200\mu A$ |
| NOISE | | | | | | |
| NF | Figure | -- | -- | 0.5 | dB | $V_{DS} = 20V$ $V_{GS} = 0V$ $R_G = 10M\Omega$ $f = 100Hz$ $NBW = 6Hz$ |
| e_n | Voltage | -- | -- | 15 | nV/ \sqrt{Hz} | $V_{DS} = 20V$ $I_D = 200\mu A$ $f = 10Hz$ $NBW = 1Hz$ |
| CAPACITANCE | | | | | | |
| C_{ISS} | Input | -- | -- | 6 | pF | $V_{DS} = 20V$ $V_{GS} = 0V$ $f = 1MHz$ |
| C_{RSS} | Reverse Transfer | -- | -- | 2 | pF | |
| C_{DD} | Drain-to-Drain | -- | 0.1 | -- | pF | $V_{DG} = 20V$ $I_D = 200\mu A$ |

Note 1 – These ratings are limiting values above which the serviceability of any semiconductor may be impaired

Available Packages:

2N3954A in TO-71 / TO-78
2N3954A available as bare die
Please contact [Micross](http://www.micross.com) for full package and die dimensions

TO-71 / TO-78 (Bottom View)



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